



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary (Typ. @ V_{GS} = -4.5V, T_A = +25°C)

V _{DSS}	R _{DS(on)}	Qg	Q _{gd}	ID
-12V	85mΩ	3.7nC	0.6nC	-2.6A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- **Battery Protection**

Features

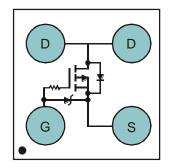
- LD-MOS Technology with the Lowest Figure of Merit: $R_{DS(on)} = 85m\Omega$ to Minimize On-State Losses Qg = 3.7nC for Ultra-Fast Switching
- Vgs(th) = -0.6V typ. for a Low Turn-On Potential
- CSP with Footprint 1.0mm × 1.0mm
- Height = 0.62mm for Low Profile
- ESD = 3kV HBM Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: U-WLB1010-4
- Terminal Connections: See Diagram Below
- Weight: 0.005 grams (Approximate)

U-WLB1010-4





Top View Equivalent Circuit

Ordering Information (Note 3)

	Part Number	Case	Packaging				
	DMP1096UCB4-7	U-WLB1010-4	3000/Tape & Reel				
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.						

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

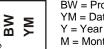
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



1W = Product Type Marking Code YM = Date Code Marking Y = Year (ex: X = 2010)M = Month (ex: 9 = September)



BW = Product Type Marking Code YM = Date Code Marking Y = Year (ex: X = 2010) M = Month (ex: 9 = September)

Date Code Key

Year	2010	20	11	2012	2013	20)14	2015	2016	20	17	2018
Code	Х	١	(Z	А		В	С	D		Ξ	F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-12	V
Gate-Source Voltage	V _{GSS}	-5	V
Continuous Drain Current (Note 5) V_{GS} = -4.5V	ID	-2.6 -2.1	А
Continuous Drain Current (Note 5) V_{GS} = -2.5V	ID	-2.4 -1.9	А
Pulsed Drain Current (Note 6)	I _{DM}	-10	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.82	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	150	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Cumple al	Min	T	Max	11	Test Condition
	Symbol	IVIIN	Тур	wax	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	51	40		1		
Drain-Source Breakdown Voltage	BV _{DSS}	-12	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$
Gate-Source Breakdown Voltage	BV _{GSS}	-6.0	-	-	V	$V_{DS} = 0V, I_G = -250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-	-	-1	μΑ	$V_{DS} = -9.6V, V_{GS} = 0V$
Gate-Source Leakage	Igss	-	-	-500	nA	$V_{GS} = -5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	-0.4	-0.6	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
		-	85	102		$V_{GS} = -4.5V, I_D = -500mA$
Static Drain-Source On-Resistance	R _{DS (ON)}	-	97	116	mΩ	$V_{GS} = -2.5V, I_D = -500mA$
		-	127	152		V _{GS} = -1.5V, I _D = -500mA
Forward Transfer Admittance	Y _{fs}	-	4	-	S	$V_{DS} = -6V, I_{D} = -500mA$
Diode Forward Voltage	V _{SD}		-0.6	-1.0	V	V _{GS} = 0V, I _S = -500mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	-	251	-		
Output Capacitance	Coss	-	359	-	pF	$V_{DS} = -6V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	-	70	-		1 = 1.00012
Total Gate Charge	Qq	-	3.7	-		
Gate-Source Charge	Q _{gs}	-	0.4	-	nC	$V_{GS} = -4.5V, V_{DS} = -6V,$
Gate-Drain Charge	Q _{qd}	-	0.6	-	nC	I _D = -500mA
Gate Charge at Vth	Q _{g(th)}	-	0.2	-		
Turn-On Delay Time	t _{D(on)}	-	17.6	-		
Turn-On Rise Time	tr	-	26.9	-		$V_{DS} = -6V, V_{GS} = -2.5V,$
Turn-Off Delay Time	t _{D(off)}	-	37.5	-	ns	$R_{G} = 20\Omega, I_{D} = -500 \text{mA}$
Turn-Off Fall Time	t _f	-	32.3	-	1	

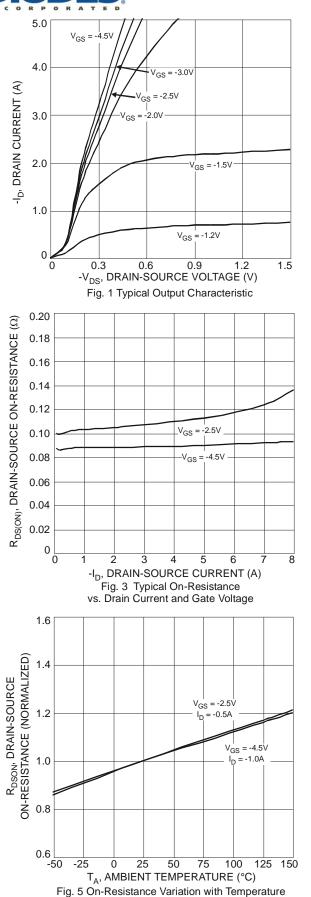
Notes:

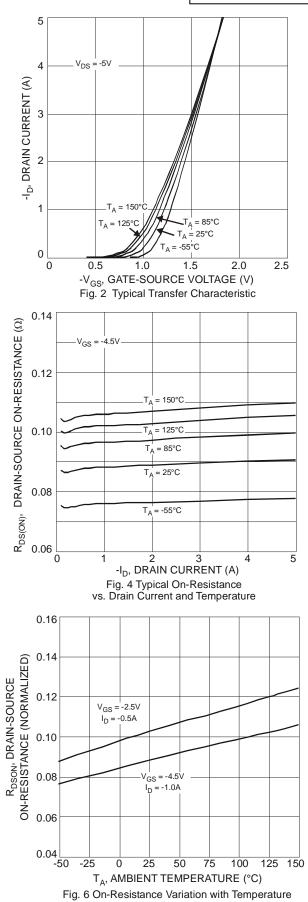
5. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.

Bevice interview and a pulse width limited by junction temperature.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.

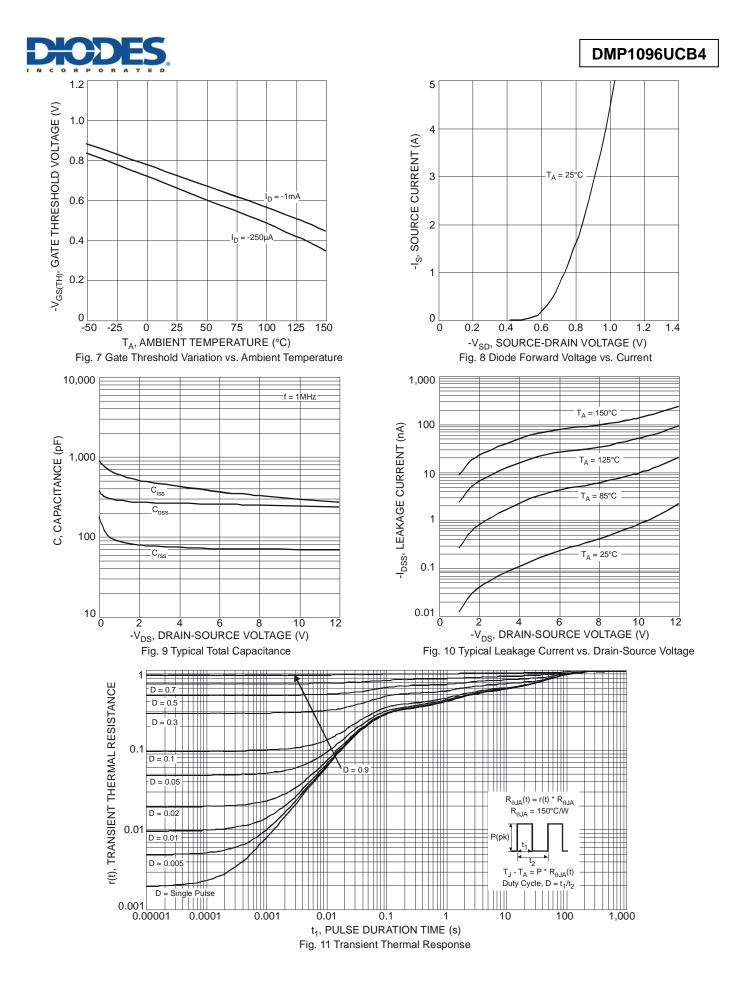


DMP1096UCB4





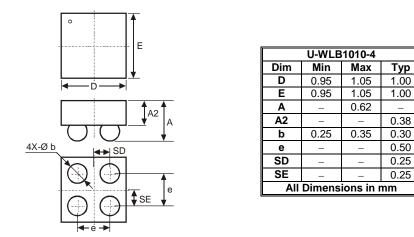
DMP1096UCB4 Document number: DS31954 Rev. 8 - 2





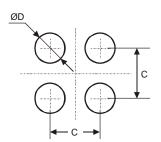
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
C	0.50				
D	0.25				



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